

SBR10150CT SBR10150CTF SBR10150CTI SBR10150CTB

Super Barrier Rectifier TM

Using state-of-the-art SBR IC process technology, the following features are made possible in a single device:

Major ratings and characteristics

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Characteristics	Values	Units
I _{F(AV)} Rectangular Waveform	10	Α
V_{RRM}	150	٧
V _F @5A, Tj=125℃	0.69	V, typ
Tj(operating/storage)	-65 to 150	$^{\circ}\mathbb{C}$

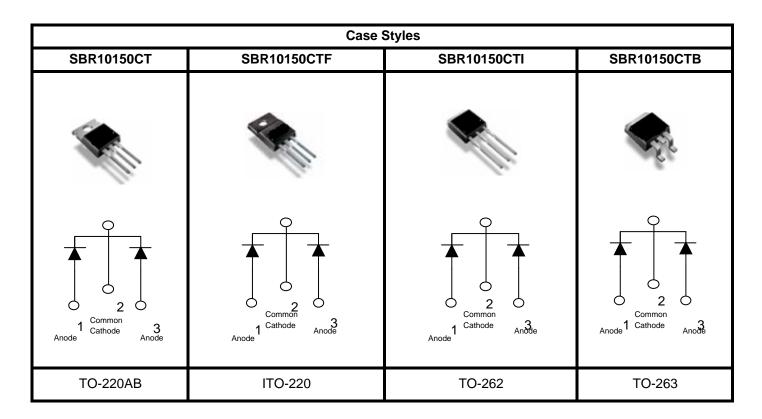
Device optimized for ultra-low forward voltage drop to maximize efficiency in **Power Supply applications**

ELECTRICAL:

- * Ultra-Low Forward Voltage Drop
- * Reliable High Temperature Operation
- * Super Barrier Design
- * Softest, fast switching capability
- * 150°C Operating Junction Temperature

MECHANICAL:

* Molded Plastic TO-220AB, TO-262, TO-263, and ITO-220 packages



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	SYMBOL			UNITS
DC Blocking Voltage Working Peak Reverse Voltage Peak Repetitive Reverse Voltage	V _{RM} V _{RWM} V _{RRM}	150		Volts
Average Rectified Forward Current (Rated V _R -20Khz Square Wave) - 50% duty cycle	Io	10		Amps
Peak Forward Surge Current - 1/2 60hz	I _{FSM}	120		Amps
Peak Repetitive Reverse Surge Current (2uS-1Khz)	I _{RRM}	2		Amps
Instantaneous Forward Voltage (per leg) $I_F = 5A; T_J = 25^{\circ}C$ $I_F = 5A; T_J = 125^{\circ}C$	V _F .	Typ 	Max 0.88 0.79	Volts
Maximum Instantaneous Reverse Current at Rated V_{RM} $T_J = 25^{\circ}C$ $T_J = 125^{\circ}C$	I _R	Typ 	Max 0.2 25	mA
Maximum Rate of Voltage Change (at Rated V_R)	dv/dt	10,000		V/uS
Maximum Thermal Resistance JC (per leg) Package = TO-220AB, TO-262, & TO-263 Package = ITO-220	R⊕ _{JC}	2 4		°C/W
Operating and Storage Junction Temperature	T₃	-65 to +150		°C

^{*} Pulse width < 300 uS, Duty cycle < 2%

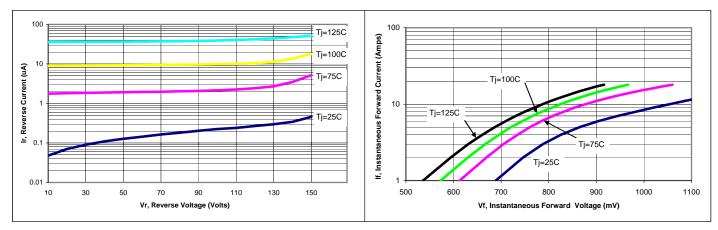


Figure 1: Typical Reverse Current (per leg)

Figure 2: Typical Forward Voltage (per leg)

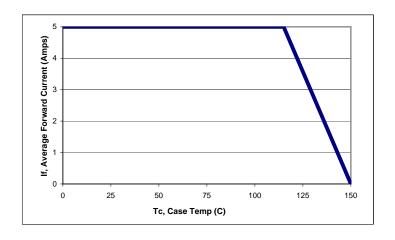


Figure 3: Current Derating, Case (per leg)

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